

isc N-Channel MOSFET Transistor

2SK642

DESCRIPTION

- Drain Current –I_D=10A@ T_C=25 $^\circ\!\!\mathbb{C}$
- Drain Source Voltage-
- : V_{DSS}=500V(Min)
- Fast Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

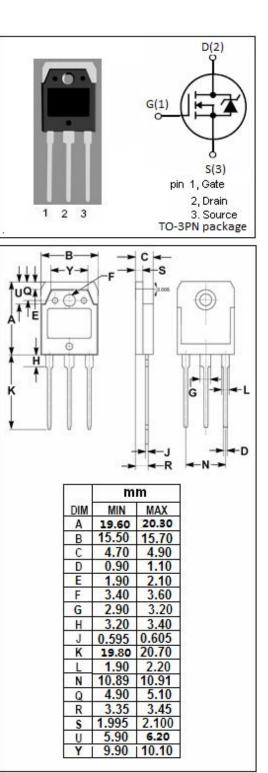
- low on–resistance
- · High speed switching
- Low drive current
- No secondary breakdown
- Suitable for switchingregulator, DC–DC convertor

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	ARAMETER	VALUE	UNIT		
V _{DSS}	Drain-Source Voltage (V _{GS} =0)	500	V		
V _{GS}	Gate-Source Voltage	±20			
ID	Drain Current-continuous@ TC=25°C	10	A		
P _{tot}	Total Dissipation@TC=25°C	100	W		
Tj	Max. Operating Junction Temperature	150	°C		
T _{stg}	Storage Temperature Range	-55~150	°C		

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT	
R _{th j-c}	Thermal Resistance, Junction to Case	1.67	°C/W	
R _{th j-a}	Thermal Resistance, Junction to Ambient	62.5	°C/W	



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• ELECTRICAL CHARACTERISTICS (Tc=25°C)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0; I _D = 10mA	500			V
$V_{GS(TH)}$	Gate Threshold Voltage	V _{DS} = 10V; I _D = 1mA	2.0		4.0	V
R _{DS(ON)}	Drain-Source On-stage Resistance	V _{GS} = 10V; I _D =5A		0.7	1.0	Ω
V _{SD}	Diode Forward Voltage	I _F = 10A; V _{GS} =0		1.0		V
I _{GSS}	Gate Source Leakage Current	V _{GS} = ±16V; V _{DS} = 0			±10	uA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =400V; V _{GS} = 0			250	uA

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